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### **Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems**

**Embedded - System On Chip (SoC)** refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

### **What are [Embedded - System On Chip \(SoC\)](#)?**

**System On Chip (SoC)** integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

#### **Details**

Product Status	Active
Architecture	MCU, FPGA
Core Processor	ARM® Cortex®-M3
Flash Size	256KB
RAM Size	64KB
Peripherals	DDR, PCIe, SERDES
Connectivity	CANbus, Ethernet, I <sup>2</sup> C, SPI, UART/USART, USB
Speed	166MHz
Primary Attributes	FPGA - 10K Logic Modules
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	400-LFBGA
Supplier Device Package	400-VFBGA (17x17)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microchip-technology/m2s010t-1vfg400">https://www.e-xfl.com/product-detail/microchip-technology/m2s010t-1vfg400</a>

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**Table 233 • RAM1K18 – Dual-Port Mode for Depth x Width Configuration 4K x 4 (continued)**

Parameter	Symbol	–1		–Std		Unit
		Min	Max	Min	Max	
Pipelined clock minimum pulse width low	$T_{PLCLKMPWL}$	1.125		1.323		ns
Read access time with pipeline register			0.323		0.38	ns
Read access time without pipeline register	$T_{CLK2Q}$		2.273		2.673	ns
Access time with feed-through write timing			1.511		1.778	ns
Address setup time	$T_{ADDRSU}$	0.543		0.638		ns
Address hold time	$T_{ADDRHD}$	0.274		0.322		ns
Data setup time	$T_{DSU}$	0.334		0.393		ns
Data hold time	$T_{DHD}$	0.082		0.096		ns
Block select setup time	$T_{BLKSU}$	0.207		0.244		ns
Block select hold time	$T_{BLKHD}$	0.216		0.254		ns
Block select to out disable time (when pipelined register is disabled)	$T_{BLK2Q}$		1.511		1.778	ns
Block select minimum pulse width	$T_{BLKMPW}$	0.186		0.219		ns
Read enable setup time	$T_{RDESU}$	0.516		0.607		ns
Read enable hold time	$T_{RDEHD}$	0.071		0.083		ns
Pipelined read enable setup time (A_DOUT_EN, B_DOUT_EN)	$T_{RDPLESU}$	0.248		0.291		ns
Pipelined read enable hold time (A_DOUT_EN, B_DOUT_EN)	$T_{RDPLEHD}$	0.102		0.12		ns
Asynchronous reset to output propagation delay	$T_{R2Q}$		1.507		1.773	ns
Asynchronous reset removal time	$T_{RSTREM}$	0.506		0.595		ns
Asynchronous reset recovery time	$T_{RSTREC}$	0.004		0.005		ns
Asynchronous reset minimum pulse width	$T_{RSTMPW}$	0.301		0.354		ns
Pipelined register asynchronous reset removal time	$T_{PLRSTREM}$	–0.279		–0.328		ns
Pipelined register asynchronous reset recovery time	$T_{PLRSTREC}$	0.327		0.385		ns
Pipelined register asynchronous reset minimum pulse width	$T_{PLRSTMPW}$	0.282		0.332		ns
Synchronous reset setup time	$T_{SRSTSU}$	0.226		0.265		ns
Synchronous reset hold time	$T_{SRSTHD}$	0.036		0.043		ns
Write enable setup time	$T_{WESU}$	0.458		0.539		ns
Write enable hold time	$T_{WEHD}$	0.048		0.057		ns
Maximum frequency	$F_{MAX}$		400		340	MHz



The following table lists the  $\mu$ SRAM in  $256 \times 4$  mode in worst commercial-case conditions when  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 241 •  $\mu$ SRAM (RAM256x4) in  $256 \times 4$  Mode**

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Read clock period	$T_{CY}$	4		4		ns
Read clock minimum pulse width high	$T_{CLKMPWH}$	1.8		1.8		ns
Read clock minimum pulse width low	$T_{CLKMPWL}$	1.8		1.8		ns
Read pipeline clock period	$T_{PLCY}$	4		4		ns
Read pipeline clock minimum pulse width high	$T_{PLCLKMPWH}$	1.8		1.8		ns
Read pipeline clock minimum pulse width low	$T_{PLCLKMPWL}$	1.8		1.8		ns
Read access time with pipeline register	$T_{CLK2Q}$		0.27		0.31	ns
Read access time without pipeline register				1.75		2.06
Read address setup time in synchronous mode	$T_{ADDRSU}$	0.301		0.354		ns
Read address setup time in asynchronous mode		1.931		2.272		ns
Read address hold time in synchronous mode	$T_{ADDRHD}$	0.121		0.142		ns
Read address hold time in asynchronous mode		-0.65		-0.76		ns
Read enable setup time	$T_{RDENSU}$	0.278		0.327		ns
Read enable hold time	$T_{RDENHD}$	0.057		0.067		ns
Read block select setup time	$T_{BLKSU}$	1.839		2.163		ns
Read block select hold time	$T_{BLKHD}$	-0.65		-0.77		ns
Read block select to out disable time (when pipelined register is disabled)	$T_{BLK2Q}$		2.09		2.46	ns
Read asynchronous reset removal time (pipelined clock)	$T_{RSTREM}$	-0.02		-0.03		ns
Read asynchronous reset removal time (non-pipelined clock)		0.046		0.054		ns
Read asynchronous reset recovery time (pipelined clock)	$T_{RSTREC}$	0.507		0.597		ns
Read asynchronous reset recovery time (non-pipelined clock)		0.236		0.278		ns
Read asynchronous reset to output propagation delay (with pipelined register enabled)	$T_{R2Q}$		0.83		0.98	ns
Read synchronous reset setup time	$T_{SRSTSU}$	0.271		0.319		ns
Read synchronous reset hold time	$T_{SRSTHD}$	0.061		0.071		ns
Write clock period	$T_{CCY}$	4		4		ns
Write clock minimum pulse width high	$T_{CCLKMPWH}$	1.8		1.8		ns
Write clock minimum pulse width low	$T_{CCLKMPWL}$	1.8		1.8		ns
Write block setup time	$T_{BLKCSU}$	0.404		0.476		ns
Write block hold time	$T_{BLKCHD}$	0.007		0.008		ns
Write input data setup time	$T_{DINCSU}$	0.101		0.118		ns
Write input data hold time	$T_{DINCHD}$	0.137		0.161		ns
Write address setup time	$T_{ADDRCSU}$	0.088		0.104		ns

**Table 245 • JTAG Programming (eNVM Only)**

<b>M2S/M2GL</b>				
<b>Device</b>	<b>Image size Bytes</b>	<b>Program</b>	<b>Verify</b>	<b>Unit</b>
005	137536	39	4	Sec
010	274816	78	9	Sec
025	274816	78	9	Sec
050	278528	84	8	Sec
060	268480	76	8	Sec
090	544496	154	15	Sec
150	544496	155	15	Sec

**Table 246 • JTAG Programming (Fabric and eNVM)**

<b>M2S/M2GL</b>				
<b>Device</b>	<b>Image size Bytes</b>	<b>Program</b>	<b>Verify</b>	<b>Unit</b>
005	439296	59	11	Sec
010	842688	107	20	Sec
025	1497408	120	35	Sec
050	2695168	162	59	Sec
060	2686464	158	70	Sec
090	4190208	266	147	Sec
150	6682768	316	231	Sec

**Table 247 • 2 Step IAP Programming (Fabric Only)**

<b>M2S/M2GL</b>					
<b>Device</b>	<b>Image size Bytes</b>	<b>Authenticate</b>	<b>Program</b>	<b>Verify</b>	<b>Unit</b>
005	302672	4	17	6	Sec
010	568784	7	23	12	Sec
025	1223504	14	33	23	Sec
050	2424832	29	52	40	Sec
060	2418896	39	61	50	Sec
090	3645968	60	84	73	Sec
150	6139184	100	132	120	Sec

Table 262 • SmartFusion2 Cortex-M3 ISP Programming (Fabric Only)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	302672	6	41	8	Sec
010	568784	10	48	14	Sec
025	1223504	21	61	29	Sec
050	2424832	39	82	50	Sec
060	2418896	44	87	54	Sec
090	3645968	66	112	79	Sec
150	6139184	108	162	128	Sec

Table 263 • SmartFusion2 Cortex-M3 ISP Programming (eNVM Only)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	137536	3	64	4	Sec
010	274816	4	104	7	Sec
025	274816	4	104	8	Sec
050	2,78,528	4	102	8	Sec
060	268480	6	102	8	Sec
090	544496	10	179	15	Sec
150	544496	10	180	15	Sec

Table 264 • SmartFusion2 Cortex-M3 ISP Programming (Fabric and eNVM)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	439296	9	83	11	Sec
010	842688	15	129	21	Sec
025	1497408	26	143	35	Sec
050	2695168	43	163	55	Sec
060	2686464	48	165	60	Sec
090	4190208	75	266	91	Sec
150	6682768	117	318	141	Sec

## 2.3.14 Math Block Timing Characteristics

The fundamental building block in any digital signal processing algorithm is the multiply-accumulate function. Each IGLOO2 and SmartFusion2 SoC math block supports 18×18 signed multiplication, dot product, and built-in addition, subtraction, and accumulation units to combine multiplication results efficiently. The following table lists the math blocks with all registers used in worst commercial-case conditions when  $T_J = 85\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 268 • Math Blocks with all Registers Used**

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Input, control register setup time	$T_{MISU}$	0.149		0.176		ns
Input, control register hold time	$T_{MIHD}$	1.68		1.976		ns
CDIN input setup time	$T_{MOCDINSU}$	0.185		0.218		ns
CDIN input hold time	$T_{MOCDINHHD}$	0.08		0.094		ns
Synchronous reset/enable setup time	$T_{MSRSTENSU}$	-0.419		-0.493		ns
Synchronous reset/enable hold time	$T_{MSRSTENHD}$	0.011		0.013		ns
Asynchronous reset removal time	$T_{MARSTREM}$	0		0		ns
Asynchronous reset recovery time	$T_{MARSTREC}$	0.088		0.104		ns
Output register clock to out delay	$T_{MOCQ}$		0.232		0.273	ns
CLK minimum period	$T_{MCLKMP}$	2.245		2.641		ns

The following table lists the math blocks with input bypassed and output registers used in worst commercial-case conditions when  $T_J = 85\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 269 • Math Block with Input Bypassed and Output Registers Used**

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Output register setup time	$T_{MOSU}$	2.294		2.699		ns
Output register hold time	$T_{MOHD}$	1.68		1.976		ns
CDIN input setup time	$T_{MOCDINSU}$	0.115		0.136		ns
CDIN input hold time	$T_{MOCDINHHD}$	-0.444		-0.522		ns
Synchronous reset/enable setup time	$T_{MSRSTENSU}$	-0.419		-0.493		ns
Synchronous reset/enable hold time	$T_{MSRSTENHD}$	0.011		0.013		ns
Asynchronous reset removal time	$T_{MARSTREM}$	0		0		ns
Asynchronous reset recovery time	$T_{MARSTREC}$	0.014		0.017		ns
Output register clock to out delay	$T_{MOCQ}$		0.232		0.273	ns
CLK minimum period	$T_{MCLKMP}$	2.179		2.563		ns

